

Appl. No. 10/816,040  
Amdt. dated 02/19/2007  
Reply to Office action of 02/02/2007

Amendments to the Specification

Please replace the last paragraph on page 3 with the following amended paragraph:

In ~~US 2002/0135953 A1 and its divisional, US 6,636,397 B2~~, Gill discloses two structures featuring a split AFM layer but in both cases the split AFM layers flank a capping layer and the free layer. The pinned layer (200) is pinned by AFM layer 104 which fully underlies it in the standard way. In US 2003/0179507 Freitag et al. describe AFM layers in wing portions of a spin valve sensor. Their configuration is similar to Gill's, with pinned trilayer 220/222/224 being fully underlaid by AFM layer 216.

Please replace the title the following new title:

A Process of Manufacturing a Side Pinned Magnetic Recording Sensor.